

RJH60F6DPK

Silicon N Channel IGBT
High Speed Power Switching

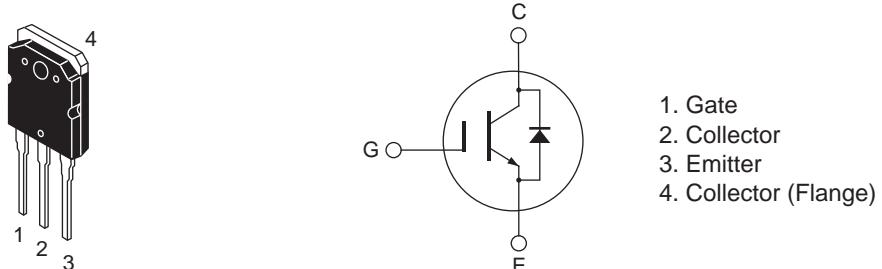
REJ03G1940-0100
Rev.1.00
Jun 18, 2010

Features

- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.35$ V typ. (at $I_C = 45$ A, $V_{GE} = 15$ V, $T_a = 25^\circ\text{C}$)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 95$ ns typ. (at $I_C = 30$ A, Resistive Load, $V_{CC} = 300$ V, $V_{GE} = 15$ V, $R_g = 5 \Omega$, $T_a = 25^\circ\text{C}$)

Outline

RENESAS Package code: PRSS0004ZE-A
(Package name: TO-3P)



Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Collector to emitter voltage	V_{CES}	600	V
Gate to emitter voltage	V_{GES}	± 30	V
Collector current	I_C	85	A
	I_C	45	A
Collector peak current	$i_{C(peak)}$ ^{Note1}	170	A
Collector to emitter diode forward peak current	$i_{DF(peak)}$ ^{Note2}	100	A
Collector dissipation	P_C	297.6	W
Junction to case thermal impedance (IGBT)	θ_{j-c}	0.42	$^\circ\text{C}/\text{W}$
Junction to case thermal impedance (Diode)	θ_{j-c}	2.0	$^\circ\text{C}/\text{W}$
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. Pulse width limited by safe operating area.

2. PW $\leq 5 \mu\text{s}$, duty cycle $\leq 1\%$

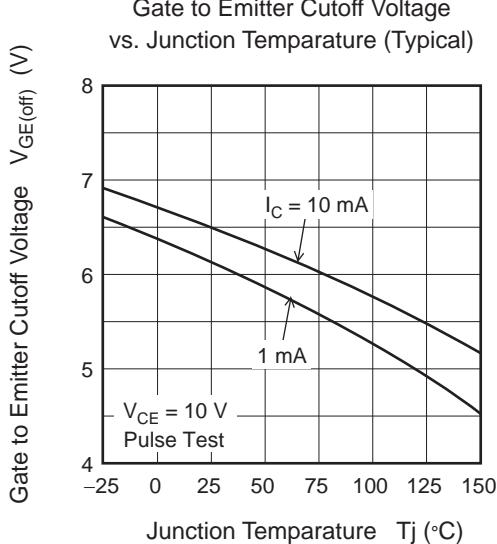
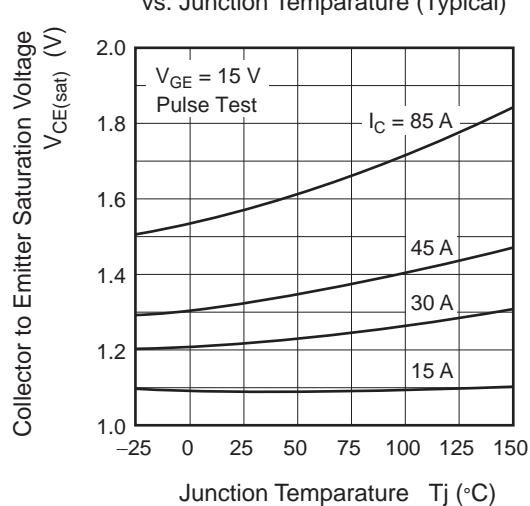
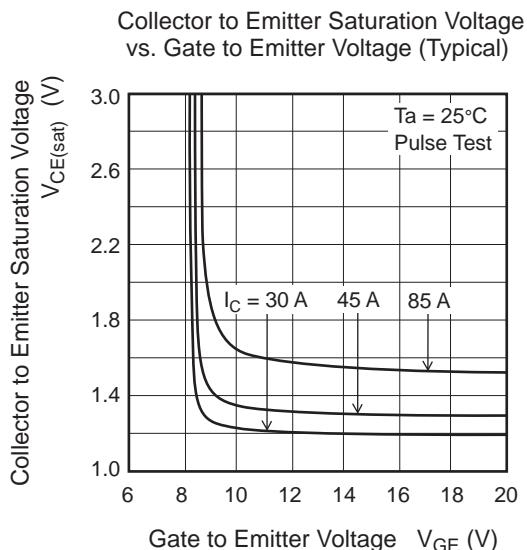
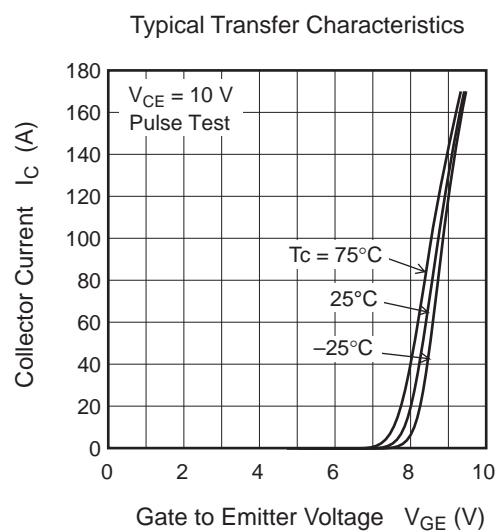
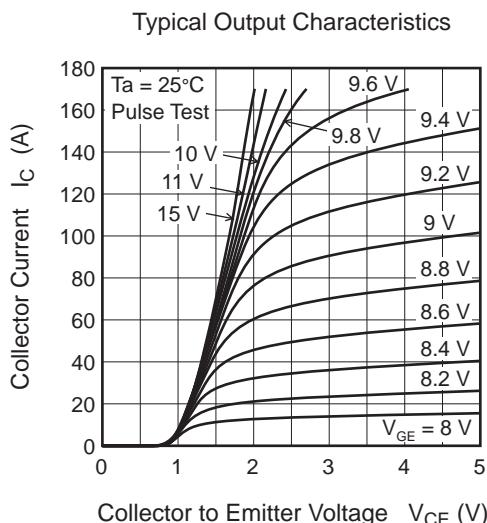
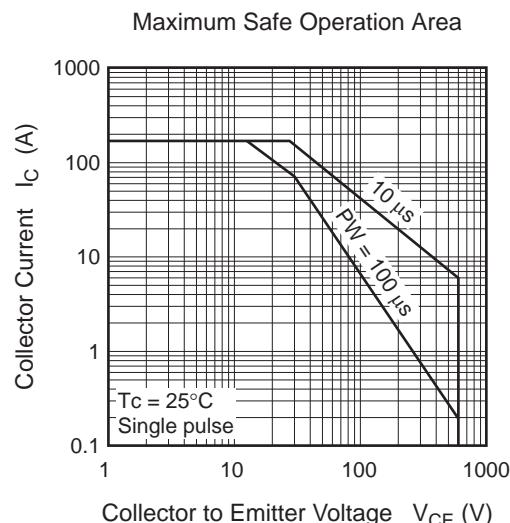
Electrical Characteristics

(T_j = 25°C)

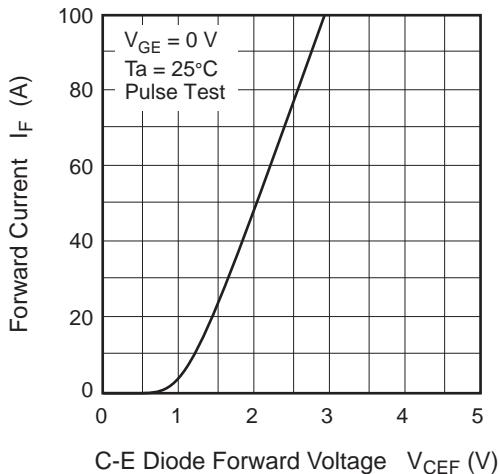
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	—	—	100	μA	V _{CE} = 600V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	—	—	±1	μA	V _{GE} = ±30 V, V _{CE} = 0
Gate to emitter cutoff voltage	V _{GE(off)}	4	—	8	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	1.35	1.75	V	I _C = 45 A, V _{GE} = 15V ^{Note3}
Input capacitance	C _{ies}	—	3800	—	pF	V _{CE} = 25 V
Output capacitance	C _{oes}	—	150	—	pF	V _{GE} = 0 V
Reverse transfer capacitance	C _{res}	—	65	—	pF	f = 1 MHz
Switching time	t _{d(on)}	—	41	—	ns	I _C = 30 A, Resistive Load
	t _f	—	24	—	ns	V _{CC} = 300 V
	t _{d(off)}	—	91	—	ns	V _{GE} = 15 V
	t _f	—	95	—	ns	R _g = 5 Ω ^{Note3}
C-E diode forward voltage	V _{ECF1}	—	1.6	2.1	V	I _F = 20 A ^{Note3}
	V _{ECF2}	—	1.8	—	V	I _F = 40 A ^{Note3}
C-E diode reverse recovery time	t _{rr}	—	140	—	ns	I _F = 20 A dI _F /dt = 100 A/μs

Notes: 3. Pulse test

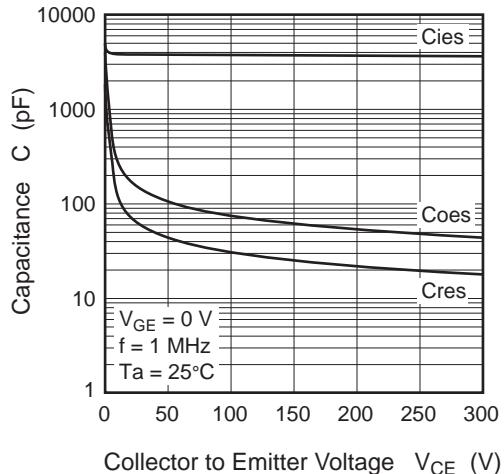
Main Characteristics



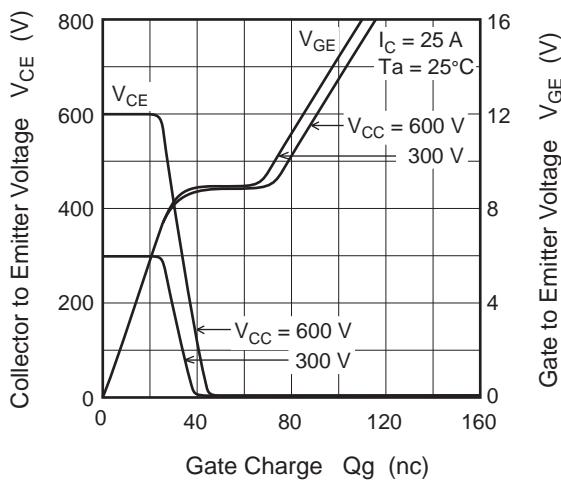
Forward Current vs. Forward Voltage (Typical)



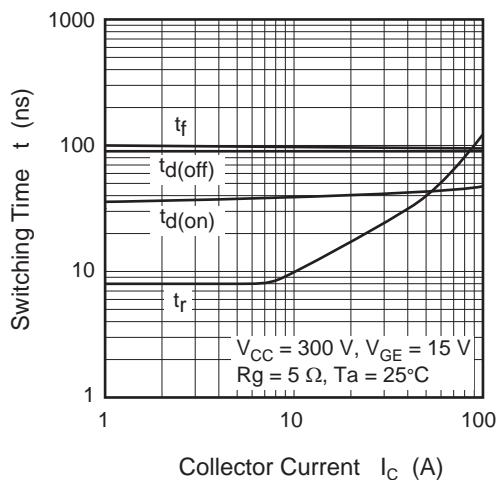
Typical Capacitance vs. Collector to Emitter Voltage



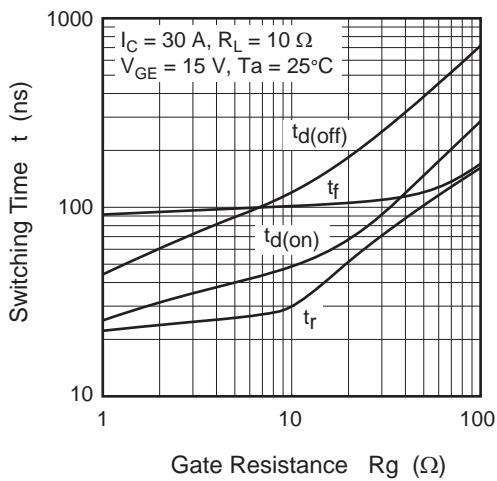
Dynamic Input Characteristics (Typical)



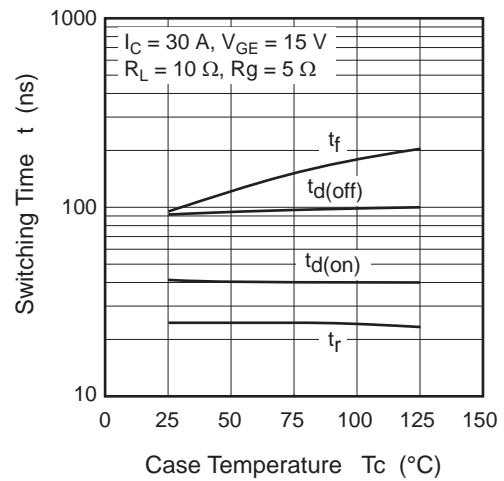
Switching Characteristics (Typical) (1)

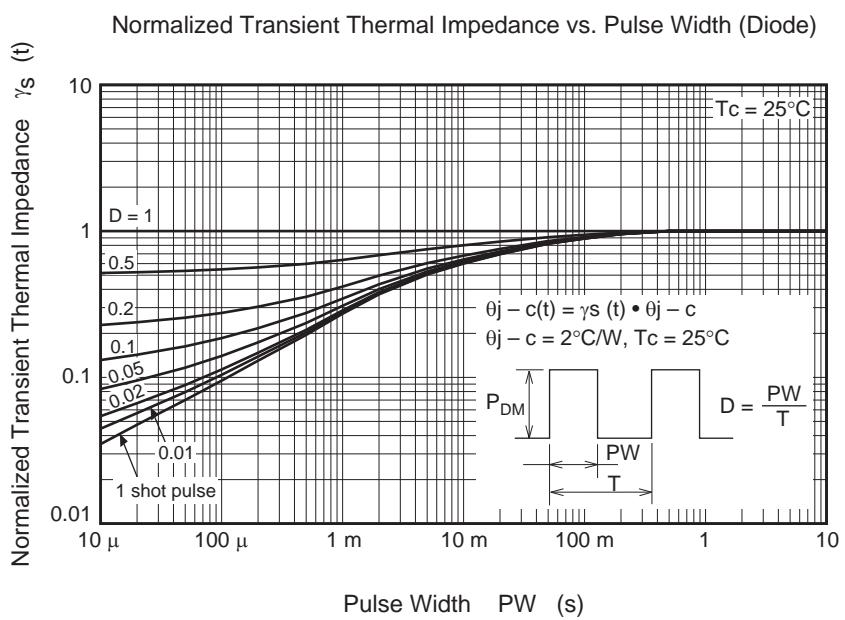
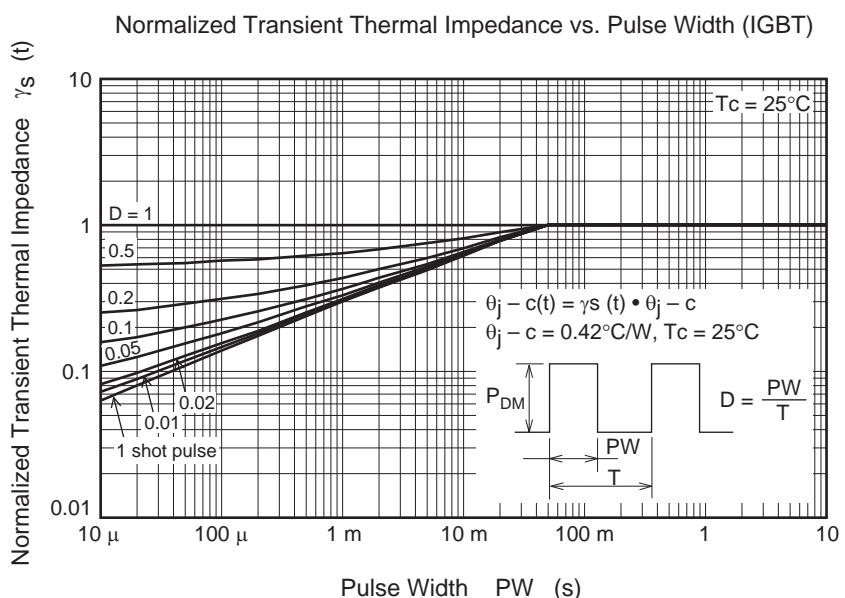


Switching Characteristics (Typical) (2)

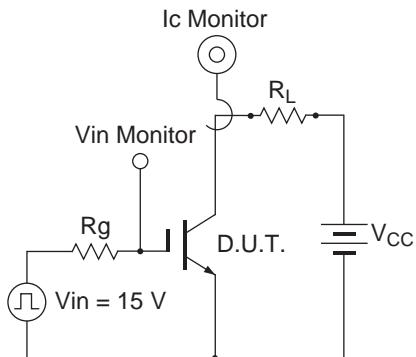


Switching Characteristics (Typical) (3)

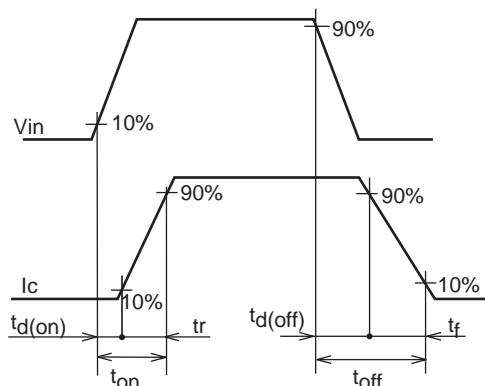




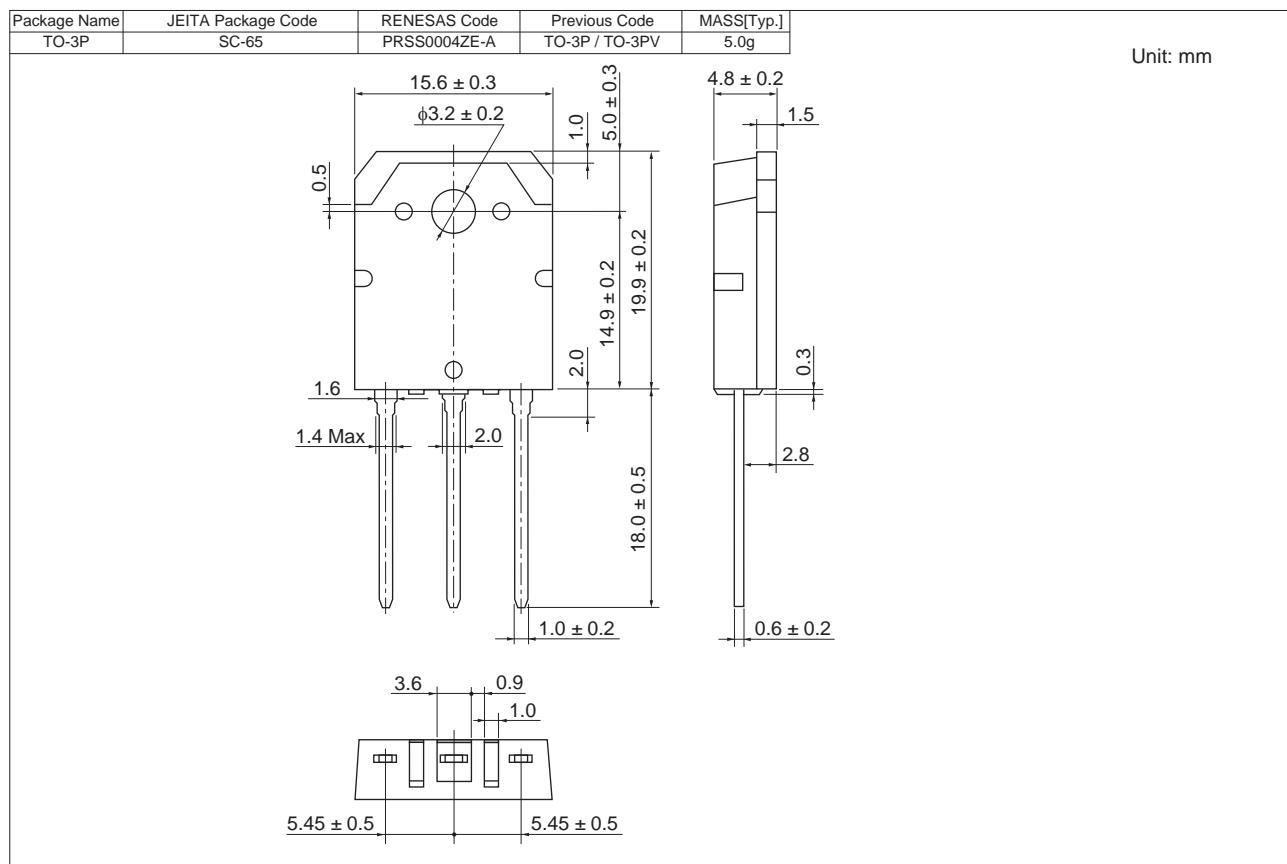
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJH60F6DPK-00-T0	360 pcs	Box (Tube)

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